Product data sheet

1. General description

General-purpose Zener diodes in an SOD123 small and flat lead Surface-Mounted Device (SMD) plastic package.

2. Features and benefits

- Total power dissipation: ≤ 590 mW
- Two tolerance series: ±2 % and approximately ±5 %
- Wide working voltage range: nominal 2.4 V to 75 V (E24 range)
- Small plastic package suitable for surface-mounted design
- · Low differential resistance
- Qualified according to AEC-Q101 and recommended for use in automotive applications

3. Applications

General regulation functions

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V_{F}	forward voltage	I _F = 10 mA	[1]	-	-	0.9	V
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[2]	-	-	350	mW
			[3]	-	-	590	mW

- [1] Pulse test: $t_p \le 300 \ \mu s$; $\delta \le 0.02$.
- [2] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.
- [3] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm².



5. Pinning information

Table 2. Pinning

Pin	Symbol	Description		Simplified outline	Graphic symbol
1	K	cathode	[1]	1 2	K []
2	Α	anode			^ _ ^
					006aaa152

^[1] The marking bar indicates the cathode.

6. Ordering information

Table 3. Ordering information

Type number	Package								
	Name	Description	Version						
BZT52-B2V4-Q to BZT52-C75-Q [1]	-	plastic surface-mounted package; 2 leads	SOD123						

^[1] The series consists of 74 types with nominal working voltages from 2.4 V to 75 V.

7. Marking

Table 4. Marking codes

Type number	Marking code	Type number	Marking code	Type number	Marking code	Type number	Marking code
BZT52-B2V4-Q	D7	BZT52-B15-Q	DS	BZT52-C2V4-Q	C1	BZT52-C15-Q	CL
BZT52-B2V7-Q	D8	BZT52-B16-Q	DT	BZT52-C2V7-Q	C2	BZT52-C16-Q	СМ
BZT52-B3V0-Q	D9	BZT52-B18-Q	DU	BZT52-C3V0-Q	C3	BZT52-C18-Q	CN
BZT52-B3V3-Q	DA	BZT52-B20-Q	DV	BZT52-C3V3-Q	C4	BZT52-C20-Q	СР
BZT52-B3V6-Q	DB	BZT52-B22-Q	DW	BZT52-C3V6-Q	C5	BZT52-C22-Q	CQ
BZT52-B3V9-Q	DC	BZT52-B24-Q	DY	BZT52-C3V9-Q	C6	BZT52-C24-Q	CR
BZT52-B4V3-Q	DD	BZT52-B27-Q	E1	BZT52-C4V3-Q	C7	BZT52-C27-Q	CS
BZT52-B4V7-Q	DE	BZT52-B30-Q	E2	BZT52-C4V7-Q	C8	BZT52-C30-Q	СТ
BZT52-B5V1-Q	DF	BZT52-B33-Q	E3	BZT52-C5V1-Q	C9	BZT52-C33-Q	CU
BZT52-B5V6-Q	DG	BZT52-B36-Q	E4	BZT52-C5V6-Q	CA	BZT52-C36-Q	CV
BZT52-B6V2-Q	DH	BZT52-B39-Q	E5	BZT52-C6V2-Q	СВ	BZT52-C39-Q	CW
BZT52-B6V8-Q	DJ	BZT52-B43-Q	E6	BZT52-C6V8-Q	CC	BZT52-C43-Q	CY
BZT52-B7V5-Q	DK	BZT52-B47-Q	E7	BZT52-C7V5-Q	CD	BZT52-C47-Q	D1
BZT52-B8V2-Q	DL	BZT52-B51-Q	E8	BZT52-C8V2-Q	CE	BZT52-C51-Q	D2
BZT52-B9V1-Q	DM	BZT52-B56-Q	E9	BZT52-C9V1-Q	CF	BZT52-C56-Q	D3
BZT52-B10-Q	DN	BZT52-B62-Q	EA	BZT52-C10-Q	CG	BZT52-C62-Q	D4
BZT52-B11-Q	DP	BZT52-B68-Q	EB	BZT52-C11-Q	СН	BZT52-C68-Q	D5
BZT52-B12-Q	DQ	BZT52-B75-Q	EC	BZT52-C12-Q	CJ	BZT52-C75-Q	D6
BZT52-B13-Q	DR	-	-	BZT52-C13-Q	СК	-	-

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
I _F	forward current			-	250	mA
I _{ZSM}	non-repetitive peak reverse current			-	see Tables 8, 9 and 10	
P _{ZSM}	non-repetitive peak reverse power dissipation		[1]	-	40	W
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[2]	-	350	mW
			[3]	-	590	mW
Tj	junction temperature			-	150	°C
T _{amb}	ambient temperature			-55	+150	°C
T _{stg}	storage temperature			-65	+150	°C

- [1] t_p = 100 μs; square wave; T_j = 25 °C prior to surge.
 [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm².

9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-a)}	thermal resistance from	in free air		-	-	350	K/W
	junction to ambient		[2]	-	-	210	K/W
$R_{th(j-sp)}$	thermal resistance from junction to solder point		[3]	-	-	55	K/W

- Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm².
- Soldering point of cathode tab.

10. Characteristics

Table 7. Characteristics

 T_i = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V_{F}	forward voltage	I _F = 10 mA	[1]	-	-	0.9	V

^[1] Pulse test: $t_p \le 300 \ \mu s$; $\delta \le 0.02$.

Table 8. Characteristics per type; BZT52-B2V4-Q to BZT52-C24-Q

 T_j = 25 °C unless otherwise specified.

BZT52 -xxx-Q			je ;	Maximum resistance		Reverse current I _R (μA)		erature cient V/K); mA	Diode capacitance C _d (pF) [1]	Non-repetitive peak reverse current I _{ZSM} (A) [2]	
		Min	Max	I _Z = 1 mA	I _Z = 5 mA	Max	V _R (V)	Min	Max	Max	Max
2V4	В	2.35	2.45	400	85	50	1	-3.5	0.0	450	6.0
	С	2.2	2.6								
2V7	В	2.65	2.75	500	83	20	1	-3.5	0.0	450	6.0
	С	2.5	2.9								
3V0	В	2.94	3.06	500	95	10	1	-3.5	0.0	450	6.0
	С	2.8	3.2								
3V3	В	3.23	3.37	500	95	5	1	-3.5	0.0	450	6.0
	С	3.1	3.5								
3V6	В	3.53	3.67	500	00 95 !	5	1	-3.5	0.0	450	6.0
	С	3.4	3.8	_							
3V9	В	3.82	3.98	500	95	3	1	-3.5	0.0	450	6.0
	С	3.7	4.1	7							
4V3	В	4.21	4.39	500	95	3	1	-3.5	0.0	450	6.0
	С	4.0	4.6								
4V7	В	4.61	4.79	500	78	3	2	-3.5	0.2	300	6.0
	С	4.4	5.0								
5V1	В	5.0	5.2	480	60	2	2	-2.7	1.2	300	6.0
	С	4.8	5.4	7							
5V6	В	5.49	5.71	400	40	1	2	-2.0	2.5	300	6.0
	С	5.2	6.0	7							
6V2	В	6.08	6.32	150	10	3	4	0.4	3.7	200	6.0
	С	5.8	6.6	1							
6V8	В	6.66	6.94	80	8	2	4	1.2	4.5	200	6.0
	С	6.4	7.2								
7V5	В	7.35	7.65	80	10	1	5	2.5	5.3	150	4.0
	С	7.0	7.9								
8V2	В	8.04	8.36	80	10	0.7	5	3.2	6.2	150	4.0
	С	7.7	8.7								
9V1	В	8.92	9.28	100	10	0.5	6	3.8	7.0	150	3.0
	С	8.5	9.6	_	10 0.5	0.3					

BZT52 -xxx-Q	Sel	Working voltage V _Z (V); I _Z = 5 mA		Maximum differential resistance $r_{dif}(\Omega)$		Reverse current I _R (μA)		Temperature coefficient S _Z (mV/K); I _Z = 5 mA		Diode capacitance C _d (pF) [1]	Non-repetitive peak reverse current I _{ZSM} (A) [2]	
		Min	Max	I _Z = 1 mA	I _Z = 5 mA	Max	V _R (V)	Min	Max	Max	Max	
10	В	9.8	10.2	70	10	0.2	7	4.5	8.0	90	3.0	
	С	9.4	10.6									
11	В	10.8	11.2	70	10	0.1 8	8 5.4	5.4 9.0	85	2.5		
	С	10.4	11.6		10							
12	В	11.8	12.2	90	10	0.1	8	6.0	10.0	85	2.5	
	С	11.4	12.7									
13	В	12.7	13.3	110	0 10	0.1	8	7.0	11.0	80	2.5	
	С	12.4	14.1									
15	В	14.7	15.3	110	110 15	0.05	10.5	9.2	13.0	75	2.0	
	С	13.8	15.6									
16	В	15.7	16.3	170	20	0.05	11.2	10.4 14.0	75	1.5		
	С	15.3	17.1									
18	В	17.6	18.4	170	20	0.05	12.6	12.4	16.0	70	1.5	
	С	16.8	19.1									
20	В	19.6	20.4	220	20	0.05	14	14.4	18.0	60	1.5	
	С	18.8	21.2									
22	В	21.6	22.4	220	25	0.05	15.4	16.4	20.0	60	1.25	
	С	20.8	23.3									
24	В	23.5	24.5	220	30	0.05 16.8	16.8	18.4	22.0	55	1.25	
_	С	22.8	25.6									

Table 9. Characteristics per type; BZT52-B27-Q to BZT52-C51-Q

 T_i = 25 °C unless otherwise specified.

BZT52 -xxx-Q	Sel	voltage V _Z (V); I _Z = 2 mA		Maximum differential resistance $r_{dif}(\Omega)$			Reverse current I _R (μA)		erature cient V/K); mA	Diode capacitance C _d (pF) [1]	Non-repetitive peak reverse current I _{ZSM} (A) [2]
		Min	Max	I _Z = 1 mA	I _Z = 5 mA	Max	V _R (V)	Min	Max	Max	Max
27	В	26.5	27.5	250	40	0.05	18.9	21.4	25.3	50	1.0
	С	25.1	28.9								
30	В	29.4	30.6	250	40	0.05	21	24.4	29.4	50	1.0
	С	28.0	32.0								
33	В	32.3	33.7	250	40	0.05	0.05 23.1	27.4	33.4	45	0.9
	С	31.0	35.0								
36	В	35.3	36.7	250	60	0.05	25.2	30.4	37.4	45	0.8
	С	34.0	38.0								
39	В	38.2	39.8	300	75	0.05	27.3	33.4	41.2	45	0.7
	С	37.0	41.0								
43	В	42.1	43.9	325	80 0	0.05	30.1	37.6	46.6	40	0.6
	С	40.0	46.0								

^[1] $f = 1 \text{ MHz}; V_R = 0 \text{ V}.$ [2] $t_p = 100 \text{ } \mu\text{s}; T_{amb} = 25 \text{ }^{\circ}\text{C}.$

BZT52 -xxx-Q	Sel					Reverse current I _R (μA)		Temperature coefficient S _Z (mV/K); I _Z = 5 mA		Diode capacitance C _d (pF) [1]	Non-repetitive peak reverse current I _{ZSM} (A) [2]
		Min	Max	I _Z = 1 mA	$_{\rm Z}$ = 1 mA $I_{\rm Z}$ = 5 mA		V _R (V)	Min	Max	Max	Max
47	В	46.1	47.9	325	90	0.05	5 32.9	42.0	51.8	40	0.5
	С	44.0	50.0								
51	В	50.0	52.0	350 100	100	0.05	5 35.7	46.6	57.2	40	0.4
	C 48.0 54.0										

- [1] f = 1 MHz; $V_R = 0 \text{ V}$. [2] $t_p = 100 \text{ } \mu \text{s}$; $T_{amb} = 25 \text{ }^{\circ} \text{C}$.

Table 10. Characteristics per type; BZT52-B56-Q to BZT52-C75-Q

 T_i = 25 °C unless otherwise specified.

BZT52 -xxx-Q					, , , , , , , , , , , , , , , , , , ,		Temperature coefficient S _Z (mV/K); I _Z = 5 mA		Diode capacitance C _d (pF) [1]	Non-repetitive peak reverse current I _{ZSM} (A) [2]	
		Min	Max	I _Z = 0.5 mA	I _Z = 2 mA	Max	V _R (V)	Min	Max	Max	Max
56	В	54.9	57.1	375	120	0.05	39.2	52.2	63.8	40	0.3
	С	52.0	60.0								
62	В	60.8	63.2	400	140	0.05	43.4	58.8	71.6	35	0.3
	С	58.0	66.0								
68	В	66.6	69.4	400	160	0.05	47.6	65.6	79.8	35	0.25
	С	64.0	72.0								
75	В	73.5	76.5	400	175	0.05	52.5	73.4	88.6	35	0.20
	C 70.0 79.0										

- [1] f = 1 MHz; $V_R = 0 \text{ V}$.
- [2] $t_p = 100 \,\mu s$; $T_{amb} = 25 \,^{\circ}C$.

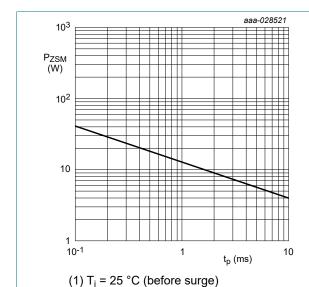


Fig. 1. Non-repetitive peak reverse power dissipation as a function of pulse duration; maximum values

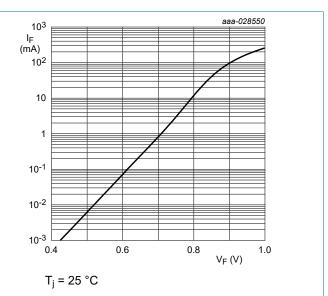


Fig. 2. Forward current as a function of forward voltage; typical values (BZT52-B/C2V4-Q)

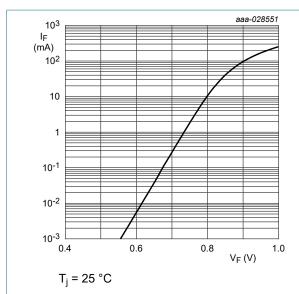


Fig. 3. Forward current as a function of forward voltage; typical values (BZT52-B/C6V8-Q)

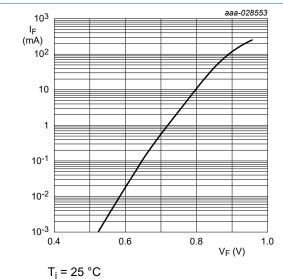


Fig. 5. Forward current as a function of forward voltage; typical values (BZT52-B/C75-Q)

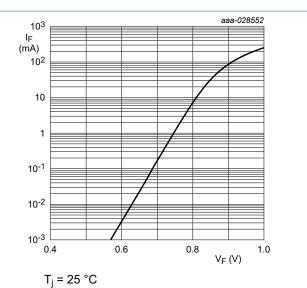


Fig. 4. Forward current as a function of forward voltage; typical values (BZT52-B/C7V5-Q)

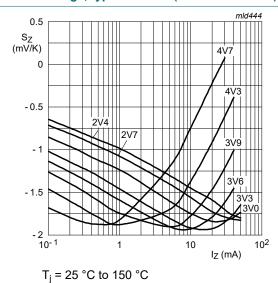


Fig. 6. Temperature coefficient as a function of working current; typical values (BZT52-B/C2V4-Q to B/C4V7-Q)

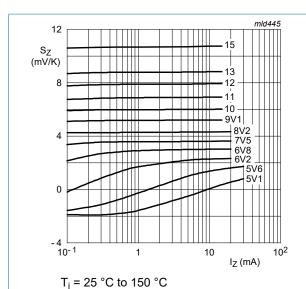


Fig. 7. Temperature coefficient as a function of working current; typical values (BZT52-B/C5V1-Q to B/C15-Q)

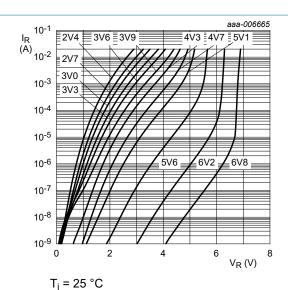


Fig. 8. Reverse current as a function of reverse voltage; typical values (BZT52-B/C2V4-Q to -B/C6V8-Q)

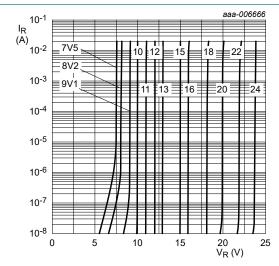


Fig. 9. Reverse current as a function of reverse voltage; typical values (BZT52-B/C7V5-Q to B/C24-Q)

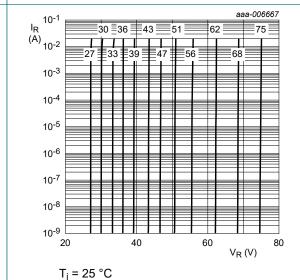


Fig. 10. Reverse current as a function of reverse voltage; typical values (BZT52-B/C27-Q to -B/C75-Q)

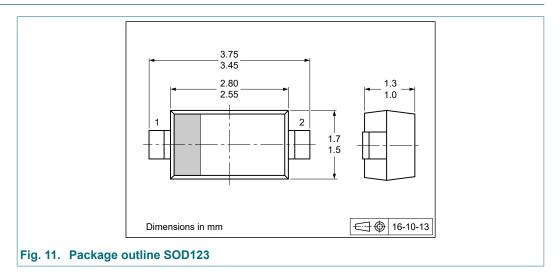
11. Test information

 $T_i = 25 \,^{\circ}C$

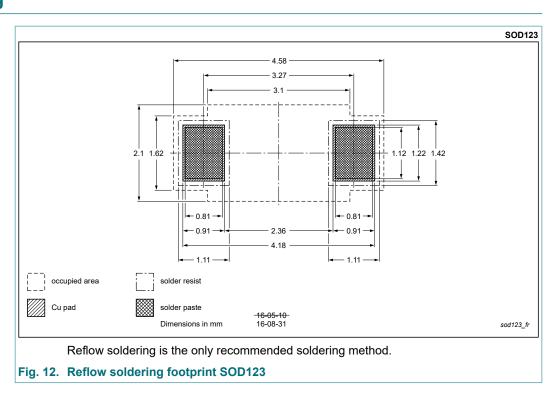
Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

12. Package outline



13. Soldering



14. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes	
BZT52-Q_SER v.2	20240603	Product data sheet	-	BZT52-Q_SER v.1	
Modifications:	Marking: BZT52-B9V1-Q and BZT52-B10-Q marking codes corrected				
BZT52-Q_SER v.1	20230329	Product data sheet	-	-	

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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BZT52-Q_SER

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